

*Customer:

Pb Free

SPECIFICATION

ITEM	CHIP LED DEVICE
MODEL	SSC-HB601
Revision Date	

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Customer

Approved by	Approved by	Approved by

Supplier

Drawn by	Checked by	Approved by



1. Features

- Package : 2.1×1.0×0.6 mm
- Untinted, Diffused flat mold
- Wavelength : 470 nm

2. Absolute Maximum Ratings

(Ta=25°C)

Parameter	Symbol	Value	Unit
Power Dissipation	P_d	72	mW
Forward Current	I_F	20	mA
Peak Forward Current	I_{FM}^{*1}	60	mA
Reverse Voltage	V_R	5	V
Operating Temperature	T_{opr}	-30 ~ +85	°C
Storage Temperature	T_{stg}	-40 ~ +100	°C

*1 I_{FM} conditions : Pulse width $T_w \leq 0.1\text{msec}$. Duty ratio $\leq 1/10$

I_{FM} applies for the condition : $T_w \leq 0.1\text{msec}$ and Duty cycle $\leq 1/10$

3. Electro-Optical Characteristics

(Ta=25°C)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Forward Voltage	V_F	$I_F=5\text{mA}$	2.7	2.9	3.1	V
Reverse Current	I_R	$V_R=5\text{V}$	-	-	10	μA
Luminous Intensity*2	I_V	$I_F=5\text{mA}$	14	24	40	mcd
Wavelength	λ	$I_F=5\text{mA}$	465	470	475	nm
Spectral Bandwidth	$\Delta \lambda$	$I_F=5\text{mA}$	-	30	-	nm
Viewing angle*3	$2\theta_{1/2}$	$I_F=5\text{mA}$	-	150	-	°

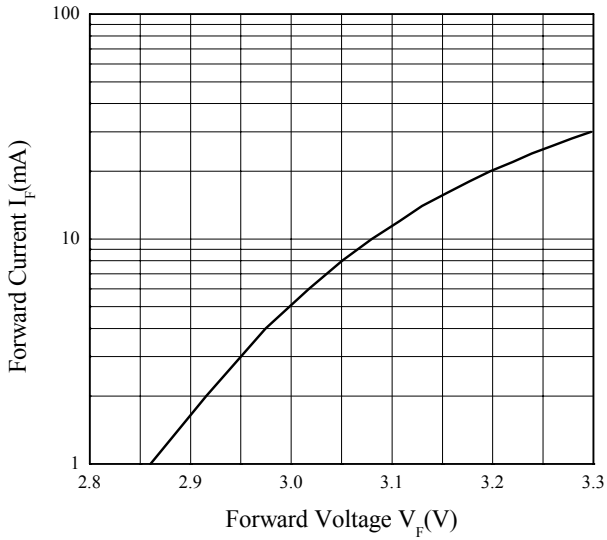
*2 The luminous intensity I_V is measured at the peak of the spatial pattern which may not be aligned with the mechanical axis of the LED package.

*3 $\theta_{1/2}$ is the off-axis where the luminous intensity is 1/2 the peak intensity.

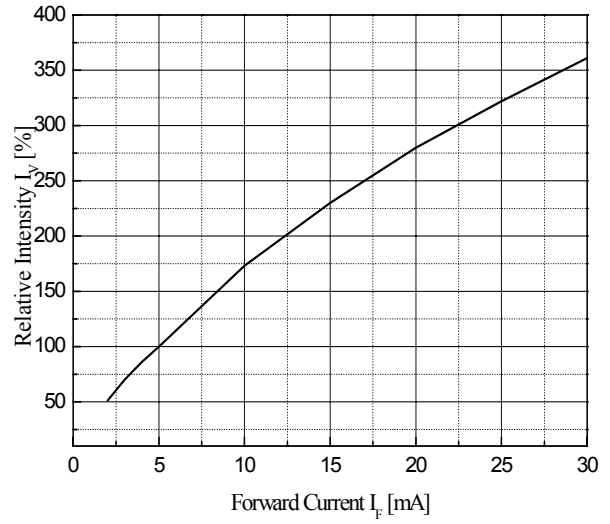
Note] All products confirm to the listed minimum and maximum specifications for electric and optical characteristics, when operated at 5mA, 20mA within the maximum ratings shown above. All measurements were made under the standardized environment of SSC.
(Tolerance: $V_F \pm 0.1\text{V}$, $I_V \pm 10\%$, $\lambda_d \pm 2\text{nm}$)

4. Characteristic Diagram

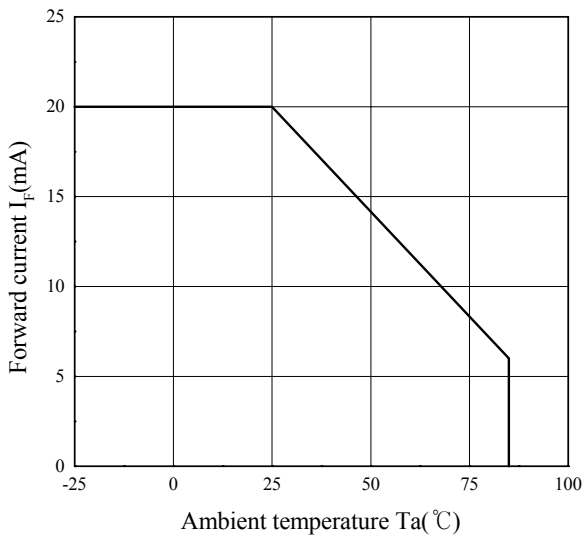
Forward Current vs Forward Voltage



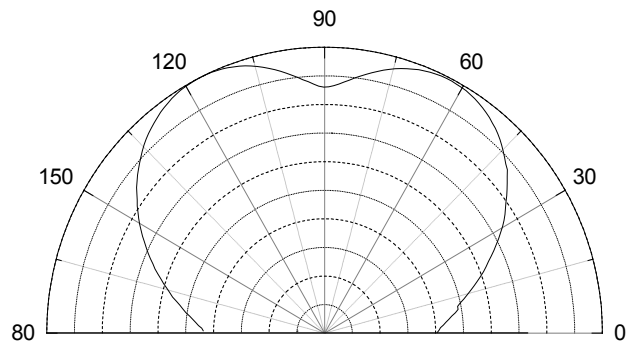
Relative Intensity I_r [%] vs Forward Current



Forward Current Derating Curve



Radiation Diagram



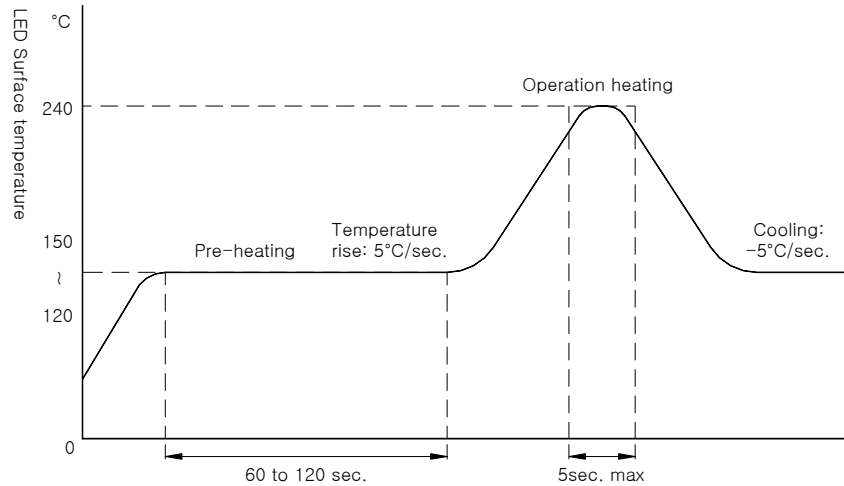
5. Soldering Profile

Reflow Soldering Conditions/ Profile

(1) Lead Solder

-Preliminary heating to be at 150°C max. for 2 minutes max.

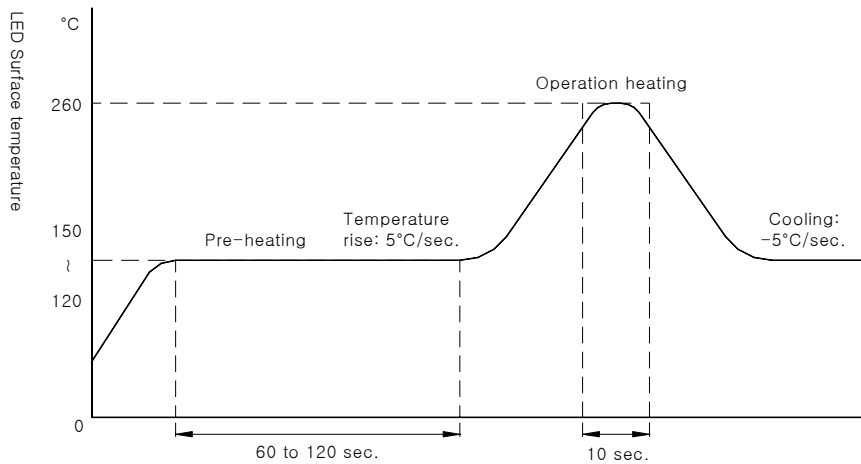
-Soldering heat to be at 240°C max. for 5 seconds max.



(2) Lead-Free Solder

-Preliminary heating to be at 150°C max. for 2 minutes max.

-Soldering heat to be at 260°C max. for 10 seconds max.

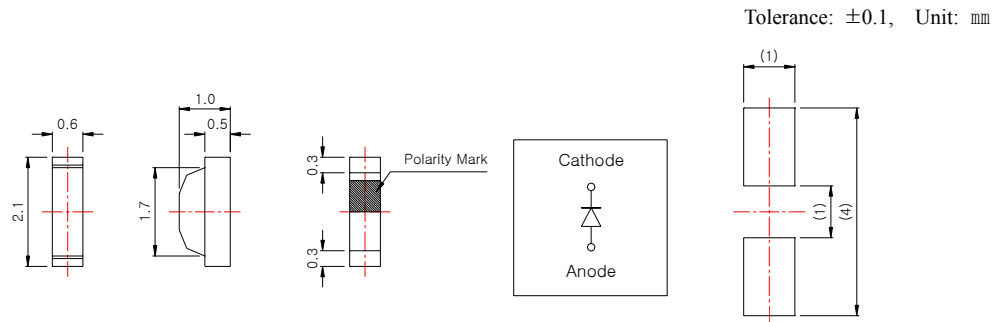


(3) Hand Soldering conditions

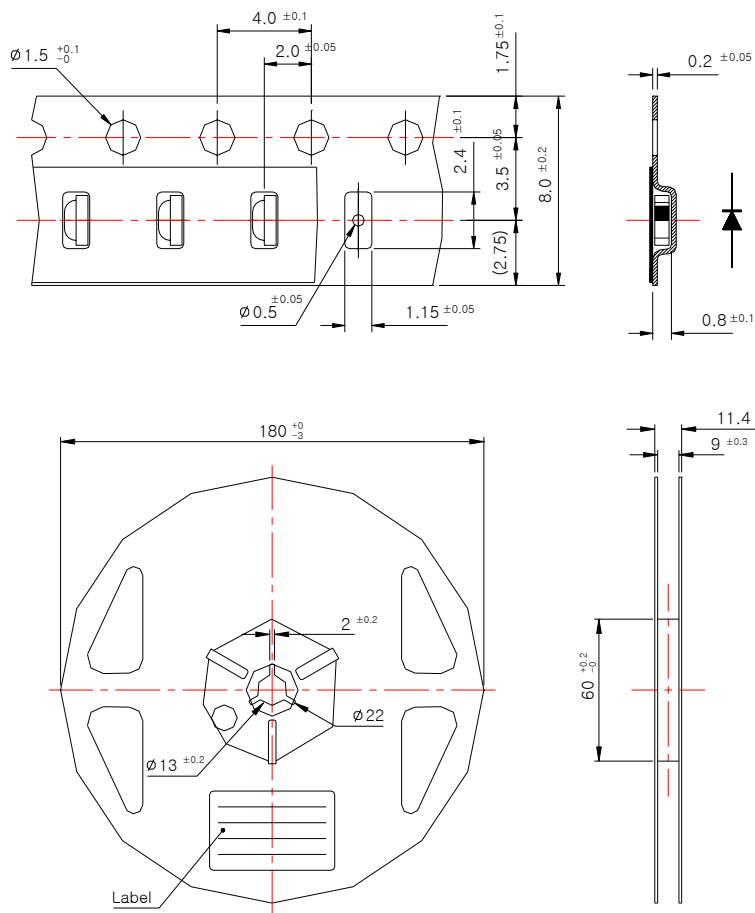
-Not more than 3 seconds @MAX280°C, under Soldering iron.

[Note] In case the soldered products are reused in soldering process, we don't guarantee the products.

6. Outline Dimension



7. Packing

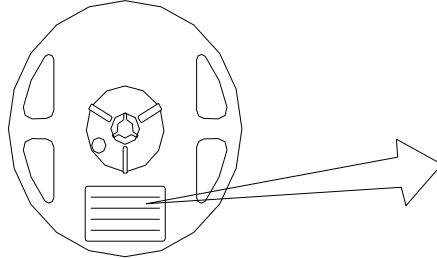






Tolerance: ± 0.2 , Unit: mm

- (1) Quantity: 3,000pcs./Reel
- (2) Cumulative Tolerance: Cumulative Tolerance/10pitches to be ± 0.2 mm
- (3) Adhesion Strength of Cover Tape: Adhesion strength to be 0.1-0.7N when the over tape is turned off from the carrier tape at 10° angle to be the carrier tape.
- (4) Package: P/N, Manufacturing data Code No. and quantity to be indicated on a damp proof Package.

8. Reel Packing Structure

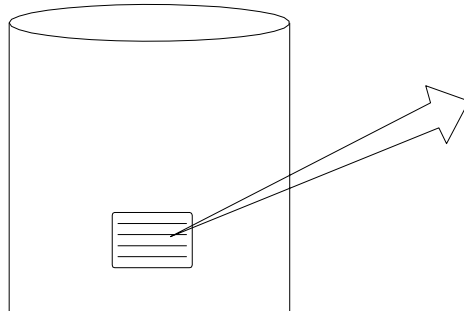
Reel







 P/N : #####  제품명 SSC-HB601 Lot No #####  수량 : 3000 	##
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Aluminum Vinyl Bag

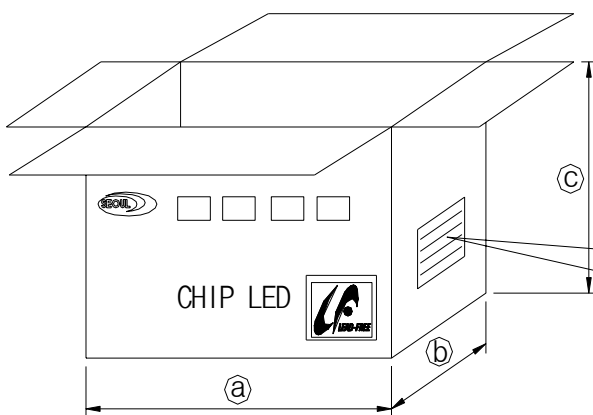


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Outer Box

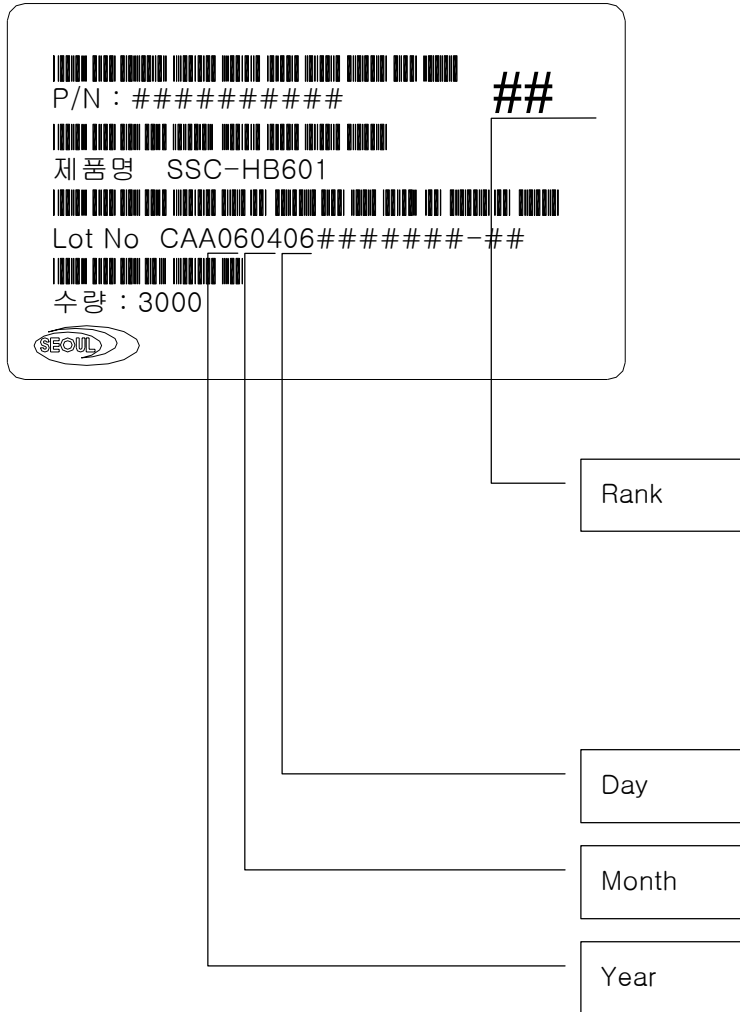
*Material : Paper (SW3B(B))



TYPE	SIZE(mm)		
	a	b	c
7inch	245	220	142

CHIP LED	
PART : SSC-HB601	_____
CODE :	_____
Q'YT :30,000EA	_____
LOT NO :	_____
DATE :	_____
 SEOUL SEMICONDUCTOR CO.,LTD	

9. Label Structure



10. Precaution for use

(1) Storage

In order to avoid the absorption of moisture, it is recommended to store in the dry box (or desiccator) with a desiccant. Otherwise, to store them in the following environment is recommended.

Temperature : 5 °C~30 °C Humidity : 60%HR max.

(2) Attention after opened

However LED is correspond SMD, when LED be soldered dip, interfacial separation may affect the light transmission efficiency, causing the light intensity to drop. Attention in followed.

a. After opened and mounted, the soldering shall be quickly.

b. Keeping of a fraction

Temperature : 5 ~ 40 °C Humidity : less than 30%

(3) In case of more than 1 week passed after opening or change color of indicator on desiccant components shall be dried 10-12hr. at 60±5 °C.

(4) In case of supposed the components is humid, shall be dried dip-solder just before.

100hr at 80±5 °C or 12hr at 100±5 °C.

(5) Any mechanical force or any excess vibration shall not be accepted to apply during cooling process to normal temp. after soldering.

(6) Quick cooling shall not be avoid.

(7) Components shall not be mounted on warped direction of PCB.

(8) Anti radioactive ray design is not considered for the products listed here in.

(9) Gallium arsenide is used in some of the products listed in this publication. These products are dangerous if they are burned or smashed in the process of disposal. It is also dangerous to drink the liquid or inhale the gas generated by such products when chemically disposed.

(10) This device should not be used in any type of fluid such as water, oil, organic solvent and etc. When washing is required, IPA should be used.

(11) When the LEDs are illuminating, operating current should be decided after considering the ambient maximum temperature.

(12) LEDs must be stored to maintain a clean atmosphere. If the LEDs are stored for 3 months or more after being shipped from SSC, a sealed container with a nitrogen atmosphere should be used for storage.

(13) The LEDs must be soldered within seven days after opening the moisture-proof packing.

(14) Repack unused products with anti-moisture packing, fold to close any opening and then store in a dry place.

(15) The appearance and specifications of the product may be modified for improvement without notice.

11. Ranks

I_V[mcd]	λ_D[nm]	V_F[V]	Bin
at I_F=5[mA]	at I_F=5[mA]	at I_F=5[mA]	
14~23	466.0~469.0	2.70~2.90	01
14~23	466.0~469.0	2.90~3.10	02
14~23	469.0~472.0	2.70~2.90	03
14~23	469.0~472.0	2.90~3.10	04
14~23	472.0~475.0	2.70~2.90	05
14~23	472.0~475.0	2.90~3.10	06
23~40	466.0~469.0	2.70~2.90	07
23~40	466.0~469.0	2.90~3.10	08
23~40	469.0~472.0	2.70~2.90	09
23~40	469.0~472.0	2.90~3.10	10
23~40	472.0~475.0	2.70~2.90	11
23~40	472.0~475.0	2.90~3.10	12